

Agenda

OSIRIS M6 Meeting

Date: 01/12/2015 - 2/12/2015

Venue: NORSTEL

Duration	Time	Topic	Organisation	Person
		First Half Day Meeting - 1/12/2015		
0:30	13:30	Coffee		
0:10	14:00	Welcome introduction	Norstel	
0:30	14:10	Contractual status	III-V Lab	D. Mazerolle / S. Delage
0:10	14:40	WP1. SiC Growth - Introduction	LIU	Örjan Danielsson
0:30	14:50	WP1. SiC substrate	Norstel	Björn Magnusson
0:30	15:20	WP1. SiC epitaxy growth	LIU	Ole Kordina
0:30	15:50	WP1. ²⁸ Si-isotope separation technique	Isosilicon	Bruno Ceccaroli
0:30	16:20	Technical discussion	Moderator: S. Delage	All
0:40	16:50	Visit of Norstel site	Norstel	
	17:30	End of First half-day Meeting	CIMAP	P. Ruterana
	19:30	Dinner	Norstel organizer	
		Second Half Day Meeting - 2/12/2015		
0:15	9:00	WP2. GaN Heterostructures LIU	LIU	Örjan Danielsson
0:15	9:15	WP2. GaN Heterostructures III-Vlab	III-V Lab	Piero Gamarra
0:10	9:30	WP3. Active Devices - Introduction	UMS	Christophe Chang
0:15	9:40	WP3. Active Devices - HEMT - III-V Lab	III-V Lab	Raphaël Aubry
0:15	9:55	WP3. Active Devices - HEMT - SiC devices	Ascatron	Adolf Schöner
0:15	10:10	WP4. Device Assessment	III-V Lab	Christian Dua
0:15	10:25	WP4. Device Assessment - STUBA	STUBA	Jaroslav Kovac
0:15	10:40	WP4. Device Assessment - Intraspec Technologies	Intraspec	Guillaume Bascoul
0:10	10:55	WP4. Device Assessment - CIMAP	CIMAP	P. Ruterana
0:20	11:05	WP5. Exploitation and Dissemination	CIMAP	P. Ruterana
0:45	11:25	Project Planning / Risk assessment - Mitigation plan	Örjan Danielsson	All
1:00	12:10	Lunch		
0:50	13:10	Final discussion - Action plan	Sylvain Delage	All
	14:00	End of Meeting		